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Structural, electronic, optical, elastic, thermodynamic and thermal transport properties of Cs₂AgInCl₆ and Cs₂AgSbCl₆ double perovskite semiconductors using a first-principles study

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In this study, we employ the framework of first-principles density functional theory (DFT) computations to investigate the physical, electrical, bandgap and thermal conductivity of Cs₂AgInCl₆-CAIC (type I) and Cs₂AgSbCl₆-CASC (type II) using the GGA-PBE method. CAIC possesses a direct band gap energy of 1.812 eV, while CASC demonstrates an indirect band gap energy of 0.926 eV. The CAIC and CASC exhibit intriguingly reduced thermal conductivity, which can be attributed to the notable reduction in their respective Debye temperatures, measuring 182 K and 135 K, respectively. The Raman active modes computed under ambient conditions have been compared with real-world data, showing excellent agreement. The thermal conductivity values of CAIC and CASC compounds exhibit quantum mechanical characteristics, with values of 0.075 and 0.25 W m⁻¹ K⁻¹, respectively, at 300 K. It is foreseen that these outcomes will generate investigations concerning phosphors and diodes that rely on single emitters, with the aim of advancing lighting and display technologies in the forthcoming generations.

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Introduction

Optoelectronics has recently seen a remarkable emergence of organic-inorganic hybrid halide perovskites (APbX₃), specifically CH₃NH₃PbI₃, due to their exceptional properties. ¹⁻³ These properties include a favorable optical band gap, high

photoluminescence quantum yield, elevated absorption coefficient, long carrier diffusion length, high carrier mobility, high tolerance to defects, and low manufacturing cost. 4-16 This rapid development and significant success have been unprecedented. Lead halide perovskite-based solar cells have shown a significant improvement in power conversion efficiency, ranging from 3.8% to an impressive 25.5%. 17-20 This significant advancement has attracted considerable attention within the scientific community, as these materials hold immense promise as potential replacements to conventional silicon-based solar cells. The remarkable photovoltaic properties of CH3NH3PbI3 have been addressed through the convergence of experimental and theoretical investigations. These studies have demonstrated the crucial role that this compound's distinctive structural and electronic characteristics play.21-26 Notably, the perovskite structure exhibits a remarkable degree of symmetry, which contributes significantly to its photovoltaic applications. Furthermore, the defect-tolerant nature of CH3NH3PbI3 further enhances its photovoltaic performance. Additionally, the valence band edge is marked by strong coupling between the Pb-6s and I-5p orbitals, resulting in an antibonding interaction. Collectively, these features synergistically contribute to the exceptional photovoltaic properties observed in CH₃NH₃PbI₃. In the field of quantum physics, it is worth noting that the intrinsic thermodynamic instability of CH3NH3PbI3 is probably grounded in the loosened chemical

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Paper

bonding of the organic cation CH_3NH^{3+} and its inherent instability. $^{27-34}$

Organic components and the harmful nature of lead (Pb²⁺), which are both essential parts of the widely used halide-based organic-inorganic hybrid perovskites, make them chemically unstable, which is the biggest problem. Despite the advantageous attributes of the CH3NH3PbI3 perovskite, including its costeffective solution treatment, remarkable defect tolerance, and ability to emit light across the visible spectrum with adjustable properties, lead halide perovskite encounters important challenges.³⁵⁻³⁸ These challenges include prolonged exposure to light, sensitivity to humidity, instability at elevated temperatures due to environmental factors, and the inherent toxicity of Pb²⁺ ions, which can accumulate biologically within ecosystems. These concerns arise because of the restriction of hazardous substances (RoHS) directive. The inherent constraints have significantly limited their practical applications.³⁹⁻⁴² The interesting matters of stability have attracted greater attention and have been partially overcome through the substitution of the organic cation with inorganic cesium ions. This development has inspired the scientific community to begin a search for metal halide perovskite compounds that possess similar photoelectric characteristics while simultaneously exhibiting non-toxicity and steadfastness.

In recent investigations, a new group of lead-free halide double perovskites (HDPs) has attracted considerable attention. These studies have shown remarkable attributes, including excellent endurance to environmental factors, inherent thermodynamic stability, and a smaller effective mass of carriers. The nontoxic double perovskites under consideration exhibit promising potential as photovoltaic absorbers, with the aim of replacing APbX₃ in halide perovskite solar cells. 43-48 Furthermore, these materials are being proposed as potential alternatives for various optoelectronic applications, including X-ray detectors, thermal neutral scintillators employed in nuclear monitoring applications, white emitting phosphors, and ultraviolet detectors. 49-52 HDP compounds have been successfully synthesized and observed in the historical world since the beginning of the 1970s. However, it is worth noting that the methodologies employed in these endeavors were limited in their different perspectives. Specifically, the synthesis of Pb-free HDPs, which exhibit a chemical formula denoted as A₂B'B"Cl₆, wherein the presence of one B'1+ and one B"3+ species effectively replaces the two harmful Pb2+ ions, has been a subject of great interest. The goal of these investigations is to produce nontoxic perovskite structures, thus allowing the way for safer and more sustainable materials. The HDP effectively categorizes these entities into two distinct classifications, namely, type I and type II, predicated upon the presence or absence of lone-pair electrons within the B' cations. HDPs of Type-I, which are dependent upon B' cations, exhibit an absence of s states housing lone pairs (s0). The manifestation of Type-II HDP is dependent upon the presence of B' cations, characterized by the possession of s electrons in a lone-pair configuration (s2). Furthermore, the utilization of leadfree HDP compounds exhibits an excellent tendency towards ecological sustainability. For a comprehensive understanding of the research history pertaining to CAIC and CASC, a recent

summary has been published, providing detailed insights. $^{53-55}$ These materials exhibit promising optoelectronic properties similar to those observed in lead-based organic–inorganic hybrid perovskites, thus making them potentially useful for various applications. $^{56-61}$

In this study, we employ the framework of first-principles density functional theory (DFT) computations to investigate the complex aspects that include the structural features, electronic conductivity, optical properties, elastic constants, and thermodynamic and thermal conductivity attributes of the DP candidate materials Cs₂AgInCl₆-CAIC (type I) and Cs₂AgSbCl₆-CASC (type II). This endeavor is dedicated to exploring the physical properties of the material and its potential as an approach to thermal conductivity. Our comprehensive theoretical investigation was conducted employing density functional theory (DFT) within the generalized gradient approximation (GGA-PBE) framework to elucidate the complex relationship between the electronic structure, optical characteristics, independent elastic moduli, Poisson's ratio, anisotropy, hardness, average sound velocity, Grüneisen parameter, Debye temperature, and the fundamental origins underlying the remarkably low thermal conductivity of CAIC and CASC compounds. Lattice dynamics calculaadditionally performed to characterize thermodynamic stability, Raman, and infrared phonons, mainly focusing on calculation of the entropy, enthalpy, free energy, and specific heat capacity of the CAIC and CASC compounds. The theoretical calculations were subjected to investigation of the experimental vibrational spectroscopy data relating to Raman and infrared measurements, revealing excellent consistency. The highthroughput calculation of elastic constants was effectively visualized through the utilization of the online ELATE analysis platform. In our investigation, we have successfully determined the fundamental properties of each material, investigating the complex state of orbital hybridization and the consequential charge transfer phenomena that underlie the development of chemical bonding behavior within the CAIC and CASC compounds.

Computational studies

The DFT calculations were elegantly executed utilizing the PAW pseudopotential method,62 which has been skillfully incorporated into the esteemed CASTEP code (CAmbridge Serial Total Energy Package). 63 The supercell dimensions of the CAIC and CASC model configurations have been systematically enhanced until the single defect state attains complete localization, showing as a 2×2 imes 2 lattice unit, including a total of 10 atoms under the influence of periodic boundary conditions. We have employed exchange and correlation (xc) functionals, specifically the generalized gradient approximation with perdew-burke-ernzerhof (GGA-PBE), in our computational calculations. The complex interaction between the fundamental constituents of ion cores and valence electrons is carefully explained with norm-conserved pseudopotentials.⁶⁴ The pseudopotentials employed in this study consider the valence states of Cs-5s²5p⁶6s¹, Ag-4s²4p⁶4d¹⁰5s¹, In-5s²5p¹, Sb-5s²5p³, and Cl-3s²3p⁵ shells. The process of geometry

optimization was executed by employing the Broyden-Fletcher-Goldfarb-Shanno minimization procedure. 65 The spatial coordinates of the atomic configurations are relaxed through the utilization of an ionic Hellmann-Feynman force convergence criterion of 0.01 eV Å^{-1} , employing a conjugate gradient minimization algorithm. The Brillouin zone was probed, employing the Monkhorst–Pack k-point⁶⁶ grid of $2 \times 2 \times 2$ for the purpose of optimizing the structures. In the sector of energy calculations, the quantum mechanical aspects come into play, where the total energy tolerance, stress, and ionic displacement appear themselves as 5.0×10^{-6} eV per atom, 0.01 eV Å⁻¹, 0.02 GPa, and 5.0×10^{-4} Å, respectively. In our calculations, the energy cutoff for the plane wave is established at 850 eV.

Results and discussion

The crystal lattices of CAIC and CASC compounds were facecentered cubic, with a space group of $Fm\bar{3}m$ (SG: #220, O_h^5).⁶⁷ The lattice length (a) for the CAIC and CASC systems was found to be 7.4195 Å and 7.606 Å, respectively. From a structural perspective, it is possible to divide the CAIC and CASC compounds into two distinct entities, wherein Ag and B" are distributed in a random manner within the same Wyckoff site (representing a disordered state) and are positioned at nonequivalent sites (representing an ordered state). The distinction between the two crystalline configurations arises due to the emergence of the superstructure denoted as $Fm\bar{3}m$, originating

from the fundamental cubic Pm3m unit cell. Fig. 1 exhibits the three-dimensional arrangement of CAIC and CASC compounds. These compounds exhibit a configuration wherein layers are constructed with alternating corner-shared octahedrons, specifically $[AgCl_6]^{5-}$ and $[B''Cl_6]^{3-}$. The extensive region that includes these octahedrons is filled by a three-dimensional network featuring Cs cations at the A-site, which are positioned at the center of the cuboctahedral space. This arrangement gives rise to a rock-salt ordering structure. 68-70 The observed characteristics of this compound exhibit enhanced stability under the influence of various external factors such as light, moisture, and ambient air within a functional environment. The luminescent phenomenon observed in these compounds is deeply connected to the presence of self-trapped excitons (STEs), which emerge because of the determined Jahn-Teller distortion exhibited by the [AgCl₆]⁵⁻ octahedron.74 Still, making a 1:1 ordered perovskite system, which has a structure like elpasolite, is very hard because of the complicated relationship between thermodynamic constraints and the difficult synthesis conditions that are needed to make it work. 75,76

The octahedral lattice structure defines the interstitial space where the Cs⁺ ions are located. It is observed that octahedra possess perfect Oh symmetry. However, due to the distinct bond lengths between Ag-Cl and B"-Cl, the dimensions of their corresponding octahedra exhibit variation. In relation to CAIC, the interatomic bonding between the silver (Ag) and chlorine (Cl) atoms has been found to be 2.792 Å, while for the indium (In) and chlorine (Cl) atoms, it is determined to be 2.455 Å. Therefore, it can be concluded that the octahedral structure

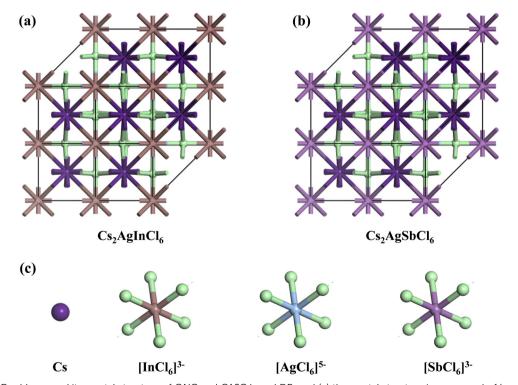


Fig. 1 (a) and (b) Double perovskite crystal structure of CAIC and CASC based DP, and (c) the crystal structure is composed of layers with alternating corner-shared $[AgCl_6]^{5-}$ and $[B''Cl_6]^{3-}$ octahedrons, and the large space located around the octahedrons is occupied by a 3D network with A-site Cs cations at the center of the cubeoctahedral space, which forms a rock-salt ordering structure.

exhibited by the [InCl₆]³⁻ species possesses a smaller size in comparison to the [AgCl₆]⁵⁻ species. In connection with CASC, it is observed that the bond lengths between Ag and Cl atoms and Sb and Cl atoms were determined to be 2.755 Å and 2.624 Å, respectively. The lengths of the apical bonds $(d_{\rm abl})$ and the equatorial bonds (d_{ebl}) are respectively given by⁷⁷

$$d_{\rm abl} = au\sqrt{2} \tag{1}$$

$$d_{\text{ebl}} = 0.5a \left[2(2u - 1)^2 + (c/a)^2 \right]^{1/2}$$
 (2)

where a and c are the lattice parameters and u are the positional parameters of the Cl atoms.

The chlorine position parameter (u), regarding bond lengths and tetragonality (c/a) can be expressed from eqn (1) and (2) and shortened to

$$u = 2d_{abl}^{2} \pm d_{abl} \frac{\left[4d_{ebl}^{2} + 2\left(d_{ebl}^{2} - d_{abl}^{2}\right)\left(c/a\right)^{2}\right]^{1/2}}{4\left(d_{ebl}^{2} - d_{abl}^{2}\right)}$$
(3)

Here, the estimations of $d_{
m abl}$ and $d_{
m ebl}$ are the same. The comparison between d_{abl} and d_{ebl} with average bond lengths $(0.5V^{1/3})$ is determined from the unit-cell volume V. The chlorine position parameter (u) for CAIC and CASC is 0.707 and 0.656 from eqn (3), respectively. Bond length, distances between octahedrons, volume, average bond lengths, and density are summarized in Table 1 for DP compounds. According to Shannon (SH) et al.78 and Radaelli (Jahn-Teller, JT) et al.,79 octahedral distortion (OD) is defined as

$$\Delta = \frac{1}{6} \sum \left(\frac{R_{\rm i} - R_{\rm av}}{R_{\rm av}} \right)^2 \tag{4}$$

$$\sigma_{\rm JT} = \sqrt{\frac{1}{3}} \sum \left[(MO)_{\rm i} - (\langle MO \rangle) \right]^2 \tag{5}$$

where R_{av} and $\langle M-O \rangle$ are the average of six bond lengths in the octahedron and can be equal to $V^{1/3}$; R_i and $(M-O)_i$ are individual bond lengths in the MO6 octahedron. SH and JT are calculated for CAIC and CASC and are 0.003×10^{-3} and 0.005×10^{-3} , as illustrated in Table 1. The OD presented by SH is more susceptible than that of JT, owing to changes in the bond length. So, the difference in the sizes of octahedra formed by [AgCl₆]⁵⁻ and [B"³⁺Cl₆]³⁻, is higher in CAIC, followed by CASC.

Electronic structure

HDPs are mainly attributed to the inherent characteristics of the direct band gap, a phenomenon that has received growing

interest after its insight by Yang et al. 80 and Volonakis et al., 81 as well as the ground-breaking research conducted by Luo et al.82 on their utilization as white light emitters. The successful experimental synthesis of HDP has yielded promising results in terms of its band gap properties. Specifically, the CAIC variant exhibits a direct band gap ranging from 3.3 to 3.5 eV, while the CASC variant possesses an indirect band gap within the range of 2.5 to 2.7 eV. 83-86 These band-gap characteristics make HDP suitable for utilization in photovoltaic applications. Additionally, it has been observed that HDP demonstrates a prolonged carrier lifetime and can be easily processed in solution form. However, it is important to note that HDP exhibits a low photoluminescence quantum yield (PLOY) of less than 0.1%, which can be attributed to the presence of parityforbidden transitions.⁸⁷ The presented graphical representation in Fig. 2 exhibits the band structures of CAIC, CABC, and CASC, which have been resolved with respect to their orbital characteristics. These insightful findings have been derived from the authoritative ref. 87. GW-BSE calculations have also been used to determine that the exciton binding energy for CAIC is 0.25 eV, where G stands for the single-particle Green's function, W stands for the screened Coulomb interaction, and BSE stands for the Bethe-Salpeter equation.⁸⁸ The optical response in the visible region is not observed due to the wide band gap of HDP. So, the best way to reduce its band gap and widen its spectral response in the visible light domain may be to alloy it with the right parts. Interestingly, it has been previously documented that the process of alloying a metal cation, specifically lanthanide ions (Dy3+, Sm3+, Tb3+), within these HDP materials contributes to the shifting of the energy difference between the valence and conduction bands and concurrently enhances the efficiency of photoluminescence.89-93

For CAIC and CASC, the band structure of the face-centered cubic phase was calculated along the lines connecting W, L, G, Z, W, and K. The band structure suggests that the valence band maximum (VBM) and the conduction band minimum (CBM) are located at W and K, the symmetry points, respectively. Fig. 3 shows the electronic band structure and density of states (DOS) of CAIC and CASC. The bandgap of CAIC and CASC is about 1.812 eV at the G-point (Fig. 3a) and 0.926 eV at the L-point (Fig. 3c). Therefore, CAIC acts as a direct and CASC acts as an indirect band gap semiconductor, and the use of the exchange correlation function provides a better result.40 DOS provides information about the complex bonding of the materials and represents the electron-electron correlation effects in a unit cell. For CAIC, the VBM contributes mainly to the Ag-4d, Cs-5p, and Cl-3p orbitals, with a moderate contribution from the In-5s

Table 1 Calculated bond lengths (d), unit-cell volume (V), average bond length $(0.4958)^{1/3}$), and chlorine positional parameter (u) of DP compounds

	Bond length (Å)					Octahedral distortion (OD)	
HDP compound	Ag-Cl	B"-Cl	Volume (V) $(\mathring{A})^3$	$0.4958V^{1/3}$	и	Shannon ⁷⁸ Δ (×10 ⁻³)	JT^{79}
$Cs_2AgB''Cl_6$ B'' = In	2.792	2.455	288.812	3.2773	0.2661	0.003	0.136
$Cs_2AgB''Cl_6$ B'' = Sb	2.755	2.624	311.140	3.3596	0.2561	0.005	0.211

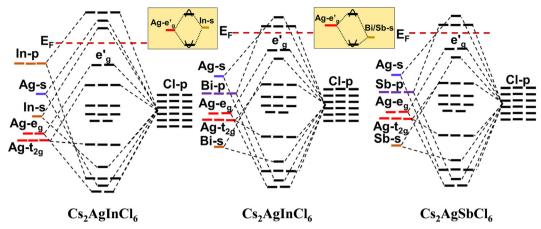


Fig. 2 The molecular orbital images were acquired through a review of the band structure of Cs₂AgInCl₆ (CAIC), Cs₂AgBiCl₆ (CABC), and Cs₂AgSbCl₆ (CASC) with an overview showing the predominant orbital attributes. The appearance of parity in the energy levels of the valence and conduction bands is effectively depicted through the utilization of Koster notation. In the inset, we observe a depiction of the hybridization process involving the hybridized Ag-eg orbitals and the In/Bi/Sb-s orbitals. This representation serves the purpose of identifying the configuration of the valence and conduction band edges' dispersion within these compounds. The intellectual property rights pertaining to the content mentioned in ref. 87 are hereby acknowledged.

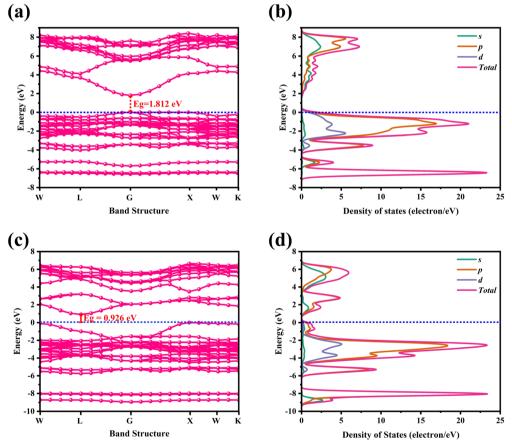


Fig. 3 Electronic band structure for CAIC and CASC compounds are calculated using the GGA-PPE method (a)–(c). In the DOS, CAIC exhibit direct band gap semiconductors, and CASC exhibit indirect band gap semiconductors (b)-(d).

and -5p orbitals in the range of -6.85 to FL (Fermi level). Moreover, the predominant contribution obtained from the Cl-3s orbital in the range of -14.295 to -12.613 eV has a noticeable contribution from the In-5s and -5p orbitals, and a significant contribution from the Cs-5s orbital occurs in the

range of -20.041 to -19.16 eV. The prominent fundamental contribution to the CBM is from the In-5s and In-5p orbitals, with a minor contribution from the Ag-5p and Cs-3p orbitals in the range of 1.9 to 9.1 eV, as shown in Fig. 3b. For CASC, the VBM contributes mainly to the Ag-4d and Cl-3p orbitals, with a

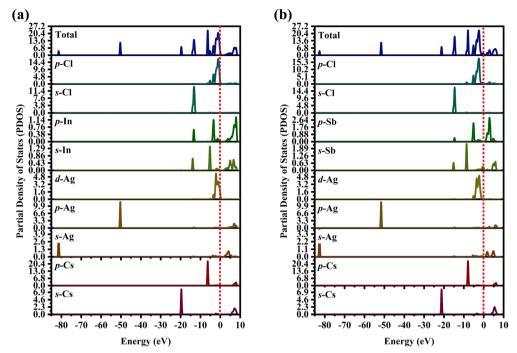


Fig. 4 Partial density of states (PDOS) for (a) CAIC and (b) CASC compounds.

moderate contribution from the Sb-5p orbital in the range of -5.47 to FL. Additionally, the predominant contribution from Cs-5p, Sb-5s, and Sb-5p orbitals ranges from -8.358 to 6.958 eV. Another is the predominant contribution obtained from the Cl-3s orbital in the range of -15.517 to 14.75 eV, with a noticeable contribution from the Sb-5s and Sb-5p orbitals, and a significant contribution from the Cs-5s orbital in the range of -21.67to -20.752 eV. The prominent fundamental contribution to the CBM is from the Sb-5s and Sb-5p orbitals, with a minor contribution from the Ag-5p and Cs-3p orbitals in the range of 1.1 to 6.5 eV, as shown in Fig. 3d.

The partial density of state PDOS of DP compounds is shown in Fig. 4. The disparity in dispersion between CAIC and CASC compounds comes from the variation in hybridization between Ag-eg and In/Sb-s states. The lowest portion of the VBM for CAIC and CASC originates from Ag-5s from -82.027 to -80.727 eV, while the middle portion originates from Ag-4p. The CBM originates mostly from the In-5s and -5p orbitals (Fig. 4a) and the Sb-5s and Sb-5p orbitals (Fig. 4b), with minor Ag-5s, Ag-4p, Cs-6s, and Cs-5p orbitals, while the top half of the VBM originates from the Ag-4d, Cs-5p, In-5s, In-5p, Cl-3s, and Cl-3p orbitals. The CBM is mainly derived from the antibonding In-s (Fig. 4a) and Sb-s states (Fig. 4b). Here, we obtain a direct bandgap with the VBM and CBM both at the G point for Type-I and an indirect bandgap at the L-point for Type-II HDP. Moreover, Ag at the B'-site and Cl at the X-sites are responsible for the electronic structures.

Charge density

According to Han et al.,94 the difference in electron density plays a crucial role in elucidating the bonding characteristics of solid materials from the electron transition, expressed mathematically as $\Delta \rho = \rho A_2 B' B'' C I_6 - [\rho A + \rho B' + \rho B'' + \rho C I]$. The electron localization function (ELF), the HDP density map, and the band-resolved analysis (Fig. 5) elucidate that the electron overlap and the HDP-active electron intensity exhibit a significant concentration that occurs in the region of the distorted [AgCl₆]⁵⁻ and the antibonding electrons of Cs atoms. The phenomenon of charge transfer in CAIC and CASC compounds

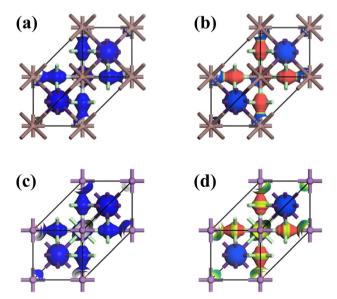


Fig. 5 Electron density map of HDP. (a)-(c) Decreased charge density (initial orbitals-1), and (b)-(d) increased charge density (final orbitals-42) for CAIC and CASC compounds. ELF = 1 (red) and 0 (blue) indicate the accumulated and vanishing electron densities, respectively.

can be attributed to the collective influence produced by the distorted [AgCl₆]⁵⁻ units and the emergence of antibonding electrons within cesium (Cs) atoms due to the existence of vacancies. Fig. 5 exhibits the chromatic representation identifying the variation in electron density. The chromatic display of yellow color corresponds to an increase in the spatial distribution of electric charge, while the appearance of blue color corresponds to a decrease in the spatial distribution of electric charge. The analysis of charge transfer in intermolecular and intramolecular systems facilitates prediction of the electronic properties, adsorption behavior, and thermodynamic stability of the mentioned systems. The quantification of the elementary charge of the electron was performed through the utilization of the Mullikan and Hirshfeld methodology, employing the analysis of CAIC and CASC compounds, and the resultant findings are shown in Table 2. The Mullikan population of the alternating corner-shared [AgCl₆]⁵⁻ octahedrons exhibits a value of 0.41 (CAIC) and 0.26 (CASC), whereas the $[B''Cl_6]^{3-}$ octahedron showcases a value of around 0.18 (CAIC) and 0.13 (CASC).

Optical properties

With the intention to gain insight into the optical characteristics, which hold the greatest importance for the usage of perovskite in optoelectronic devices, an in-depth understanding was achieved by employing the complex dielectric function $\varepsilon(\omega) = \varepsilon_1(\omega) + i\varepsilon_2(\omega)$, as expounded upon in ref. 95 and 96. The frequency-dependent complex dielectric function, $\varepsilon(\omega)$, has been computed, which includes both the real component, $\varepsilon_1(\omega)$, and the imaginary component, $\varepsilon_2(\omega)$. In this investigation, determination of the imaginary component, $\varepsilon_2(\omega)$, was achieved by performing a direct analysis of the electronic structure employing the GGA-PBE method. However, the real component, $\varepsilon_1(\omega)$, was derived through application of the Kramers-Kronig correlation technique, as discussed in ref. 97 and 98. Fig. 6 exhibits the real $[\varepsilon_1(\omega)]$ and imaginary $[\varepsilon_2(\omega)]$ components of the static dielectric function, correspondingly. The real component $[\varepsilon_1(\omega)]$ of the dielectric function serves as an accurate measure of the refractive index. In the field of optical phenomena, it is observed that an enhanced refractive index corresponds to an enhanced probability of light absorption. The imaginary component appears to be the quantum mechanical phenomenon of transitioning from states of

Table 2 Mullikan and Hirshfeld charge analysis of HDP

	CAIC		CASC			
Species ion	Mulliken charge (e)	Hirshfeld charge (e)	Species ion	Mulliken charge (e)	Hirshfeld charge (e)	
Cl1	-0.49	-0.18	Cl1	-0.47	-0.18	
Cl2	-0.4	-0.18	Cl2	-0.47	-0.18	
Cl3	-0.49	-0.18	Cl3	-0.47	-0.18	
Cl4	-0.49	-0.18	Cl4	-0.47	-0.18	
Cl5	-0.49	-0.18	Cl5	-0.47	-0.18	
Cl6	-0.49	-0.18	Cl6	-0.47	-0.18	
Ag	0.09	0.30	Ag	_	0.25	
In	0.70	0.35	In	0.99	0.41	
Cs	1.08	0.21	Cs	0.92	0.21	
Cs	1.08	0.21	Cs	0.92	0.21	

occupied bands to states of unoccupied bands. In Fig. 6a-c, we present the electronic contribution within the dielectric function, which has been evaluated employing the GGA-PPE methods. Following this, in Fig. 6c and d, we depict the imaginary part $[\varepsilon_2(\omega)]$ of the dielectric function, which has been determined using the DFPT technique. The measured static values for CAIC and CASC are 3.56 at a wavelength of 277 nm and 5.77 at a wavelength of 841.80 nm, respectively. These values exhibit excellent agreement with previously reported results. 33,60 The theoretical findings reveal an evident difference between the real static value of the CAIC compound and that of the CASC. This difference suggests that the ionic contribution to the dielectric constant is comparatively less significant in the case of CAIC (3.5, at a wavelength of 145.57 nm) in contrast to CASC (3.8, at a wavelength of 346.74 nm), as visually depicted in Fig. 2b-d.

The complex refractive index $m(\lambda)$ can be expressed as a sum of the real part of the refractive index, $m_r(\lambda)$, and the imaginary part, $im_i(\lambda)$, where λ represents the wavelength in free space. The real component of the refractive index can be recognized as the ratio of the velocity of light in a vacuum to the velocity of the phase of an electromagnetic wave propagating through the given medium. The complex component of the refractive index is deeply connected to the absorption coefficient through the expression of $4\pi \text{mi}/\lambda$. In the spectrum of refractive indices, exclusively the phenomenon of scattering appears itself. In the category of complex indices, one must recognize the potentiality of both scattering and absorption phenomena. An extensive calculation and comprehensive review of the refractive indices for CAIC and CASC have been undertaken. In Fig. 7, the depicted quantities are the refractive indices, both real and imaginary, related to the materials CAIC and CASC. These indices are presented as functions of wavelength. The theoretical findings reveal that the refractive index, when examined at a wavelength of 263.77 nm, attains its highest value of 1.92 for CAIC (as illustrated in Fig. 7a). Similarly, at a wavelength of 792.597 nm, the refractive indices reach a maximum value of 2.427 for CASC (as depicted in Fig. 7b), which correlates directly with the real component of the dielectric tensor. The observed increase in the CASC can be attributed to the associated decrease in the energy band gap when compared to the CAIC. The refractive index exhibits an increase in value, reaching its maximum at the first transition energy, which corresponds to the electron's leap from the valence band to the conduction band. The observed maxima exhibit an evident shifting towards the lower energy spectrum, thereby signifying an affinity for the transition to appear at lower energy levels. The observed behavior in the case of CASC exhibits abnormalities arising from the associated indirect band gap. In this scenario, a significant abundance of phonon scattering phenomena will appear. The refractive indices of CASIC display significant deviations from those of CAIC for wavelengths exceeding 220 nm (as shown in Fig. 7a-c). The complex refractive indices of both CAIC and CASC exhibit notable absorption features at approximately 137.4 and 141 nm, respectively. It is worth noting that CAIC displays a local minimum in these absorption regions, as depicted in Fig. 7c and d. In contrast, it is observed that CASC exhibits significantly greater

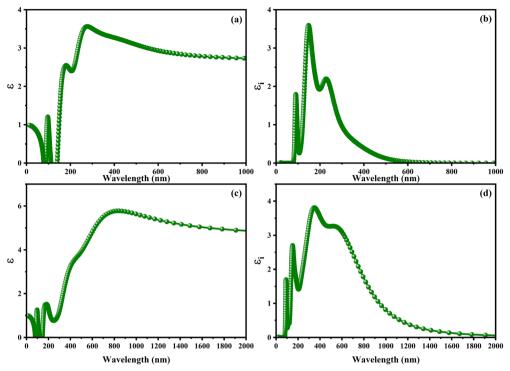


Fig. 6 Optical properties of (a)–(c) real $[\varepsilon_1(\omega)]$ and (b)–(d) imaginary $[\varepsilon_2(\omega)]$ parts of the static dielectric function for CAIC and CASC compounds.

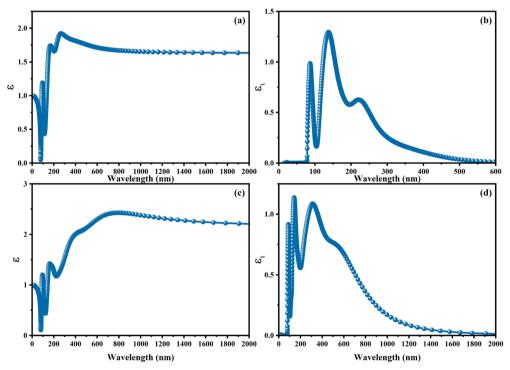


Fig. 7 Optical properties of (a)–(c) real $[m_r(\lambda)]$ and (b)–(d) imaginary $[im_i(\lambda)]$ parts of the refractive index for CAIC and CASC compounds.

absorption compared to CAIC when considering wavelengths exceeding 195 nm. The refractive indices of CAIC in the UV and visible regions are very small, while they experience a significant increase for CASC, predominantly in the nearinfrared region. Based on our analysis, it is inferred that the

refractive index of CASC exhibits an enhancement, thereby leading to a corresponding enhancement in its optical characteristics.

Fig. 8 exhibits the absorption spectra, reflectivity, optical conductivity, and loss energy related to the CSIC and CASC compounds. The CSIC and CASC compounds exhibited evident

absorption, commencing at approximately 78.80 nm, and reaching their peak at 87.14 and 138 nm, respectively. These absorption patterns can be attributed to vibrational phenomena arising from the interplay between B" and Cl atoms, as visually depicted in Fig. 8a and b. The compound under investigation exhibits an extensive optical absorption phenomenon at wavelengths below 300 nm, while a comparatively weak absorption is observed at 282 nm for CAIC (Fig. 8a). The absorption at 282 nm corresponds to an allowed transition, whereas the absorption at this wavelength is associated with a parity-forbidden transition. The absorption spectra with wavelengths exceeding 400 nm exhibit a direct correlation with the emission of free excitons in the context of CASC compounds, as visually depicted in Fig. 8b. The reflectivity of the CAIC and CASC compounds, when probed at a wavelength of 80.90 nm, has been theoretically determined to be 0.665 and 0.828, respectively. These results suggest a notable degree of reflectivity exhibited by these compounds. The absence of absorption peaks is theoretically detected beyond the 200 nm wavelength for compounds of CASC. However, the observed peaks falling within the wavelength range of 360 to 600 nm can be attributed to the octahedral bonding interactions of $[B''Cl_6]^{3-}$, as visually represented in Fig. 8c and d. At a wavelength of 80.90 nm, most of the detected absorptions are caused by vibrations caused by the interaction between Ag and Cl atomic entities. Fig. 8e and f exhibit the optical conductivity related to the CAIC and CASC compounds. The CAIC successfully exhibits optical conductivity within the wavelength range of 80 to 600 nm, with its peak value reaching 2.99 at 89 nm. Similarly, the CASC demonstrates

optical conductivity within the wavelength range of 80 to 1000 nm, with its maximum value recorded as 3.674 at 145.7 nm. These findings are visually represented in Fig. 8f. The depiction of the loss function for CAIC and CASC can be observed in Fig. 8g and h. The observation of energy loss in photoelectrons occurs within the wavelength range of 72 to 84 nm. Particularly, the maximum energy loss value of 66.125 is observed at a wavelength of 78.55 nm for the CAIC system, while the minimum energy loss value of 27.038 is observed at a wavelength of 80.189 nm for the CASC system. These findings are illustrated in Fig. 8g and h.

Phonon vibrational properties

To go deeper into the quantitative understanding of the thermodynamic characteristics resulting from the collective vibrations of atoms within a crystalline structure, our investigation will be directed towards elucidating their temperature-dependent behavior. Phonon oscillation emerges as an essential field within condensed matter systems, with a specific focus on the thermal behavior of solids in correspondence to temperature. 99-103 The thermodynamic metastability of a compound refers to its enthalpy above the ground-state phase(s) under zero pressure and a temperature of 0 K. In the scenario of polymorphs, the compound with the lowest energy and same composition is considered, whereas for materials undergoing phase separation, the energy of the stable decomposition products that are separated by phases is combined in a linear approach. Under situations of applied thermodynamics, such as temperature and pressure variations, the relative stability of different phases may undergo changes. However, it is improbable that the overall

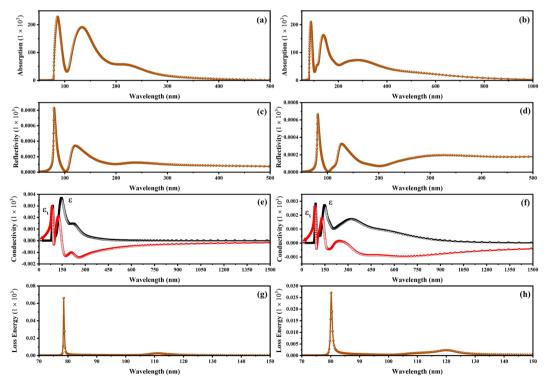


Fig. 8 Other optical properties of CAIC and CASC compounds, including (a) and (b) absorption coefficient, (c) and (d) reflectivity (R), (e) and (f) optical conductivity, and (g) and (h) energy loss spectrum using GGA-PBE methods. We used a dividing factor of 1000 to normalize the figures

thermodynamic scale of metastability deviates much from the one seen at zero temperature and pressure. The greater excessenthalpy phases are characterized as being "more" metastable, and the concept of metastability is quantified in millielectron volts per atom (10 meV per atom ~ 1 kJ mol⁻¹ atoms), with normalization per atom rather than per formula unit. 104,105 However, the presence of cation defects results in the system transitioning into a state with holes, known as a hole-doped state. On the other hand, the existence of oxygen vacancies creates defect levels that are located close to the lowest energy level of the conduction band. The presence of ordered oxygen vacancies inside HfO layers is thermodynamically advantageous and leads to the development of metallic properties in this system. 106 This phenomenon arises as a result of charge transfer occurring between the vacancy site and the hafnium dangling bond. The electronic properties of Nb- and Tc-doped systems were seen to undergo a transition from insulating to p- and ntype half-metallic ferromagnetic states. One notable aspect of the observation is that oxygen ions exhibit spin polarization, resulting in a magnetic moment of about 0.12 mB per atom. Moreover, these ions play a predominant role in the conductivity of the Nb-doped system. 107

The determination of the lattice or total energy (E_{tot}) needs a thorough computation of the interplay between electronic and nuclear repulsion through the utilization of first-principles calculations. The evaluation of the relative stability of CAIC and CASC can be achieved through the utilization of entropy, enthalpy, Helmholtz free energy, and specific heat capacity to examine their thermodynamic characteristics. Moreover, the Raman-active modes of the CAIC and CASC systems were

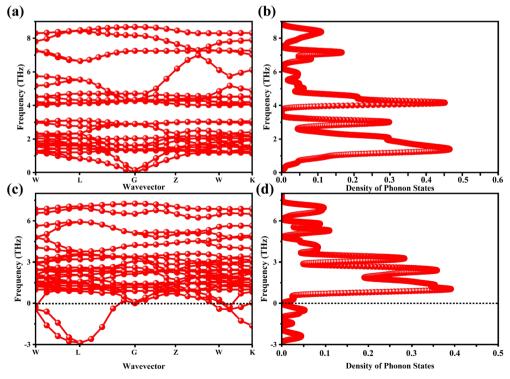
computed employing the density functional theory (DFT) approach. The relative stability of the CAIC and CASC can be influenced by the zero-point energies of 0.207 and 0.159 eV, respectively. In Fig. 9, we observe the phonon vibrational and vibrational density of phonon states (VDOS) for the CAIC and CASC systems. The stability of a crystalline structure is ensured when the phonon frequencies of a given unit area show positive values for CAIC and negative values for CASC. This shows that CASC is dynamically unstable. If specific frequencies within a designated spatial region show complex values, commonly known as soft modes, it indicates a state of instability within the system. The evaluation of the phonon density of states is performed using the fundamental principles of phonon theory. This integration is performed within the framework of the quasi-harmonic approximation and can be expressed mathematically using the following equations:

$$F = 3nNk_{\rm B}T \int_0^{\omega_{\rm max}} \ln \left\{ 2 \sinh \left(\frac{\hbar \omega}{2k_{\rm B}T} \right) \right\} g(\omega) d\omega \qquad (6)$$

$$S = 3nNk_{\rm B} \int_{0}^{\omega_{\rm max}} \frac{\left(\frac{\hbar\omega}{2k_{\rm B}T}\right) \coth\left(\frac{\hbar\omega}{2k_{\rm B}T}\right)}{-\ln\left\{2\sinh\left(\frac{\hbar\omega}{2k_{\rm B}T}\right)\right\}g(\omega)\mathrm{d}\omega}$$
(7)

$$C_{\rm v} = 3nNk_{\rm B} \int_0^{\omega_{\rm max}} \left(\frac{\hbar\omega}{2k_{\rm B}T}\right)^2 {\rm csch}^2 \left(\frac{\hbar\omega}{2k_{\rm B}T}\right) g(\omega) {\rm d}\omega \tag{8}$$

Here, the symbol $k_{\rm B}$ corresponds to the fundamental constant known as the Boltzmann constant. The variable ω_{max} signifies



(a)-(c) Phonon-dispersion curves and (b)-(d) density of phonon states for CAIC and CASC compounds.

the upper limit of the frequency spectrum associated with phonons. The symbol n represents the quantity of atoms contained within a single unit cell. N, on the other hand, denotes the total number of unit cells present. Lastly, the function $g(\omega)$ characterizes the normalized vibrational density of states (VDOS) with $\int_0^{\omega_{\text{max}}} g(\omega) d\omega = 1$. The concept of the "quasiharmonic approximation" arises from a methodology in which the evaluation of the Helmholtz free energy, a function dependent on both volume and temperature, is conducted by employing the harmonic approximation for a particular volume. The inclusion of anharmonic contributions is confined to the influence of changes in the system volume on the phonon frequency.

The heat capacity of a substance provides information about vibration properties and energy band structures. To obtain CAIC and CASC, thermodynamic parameters, including the vibrational entropy (E), the vibrational enthalpy (S), the Helmholtz free energy (H), and the specific heat capacity (C_v) at constant volume, have been accurately estimated using the quasi-harmonic approximation method to study the thermodynamic properties of materials. The E, S, H, G, and C_v can be calculated from eqn (6)–(8). Fig. 10 shows the relative thermodynamic parameters of the CAIC and CASC. At 300 K formation, E obtained about 1.48 and 1.54 eV for CAIC and CASC, as shown in Fig. 10a-c. When the temperature is 1000 K, the E increases to 7.853 and 7.79 eV for CAIC and CASC, respectively. The formation of H for CAIC at 300 K is 0.61 eV and is similar to that for CASC. When the temperature increases to 1000 K, the H is 2.39 and 2.29 eV for CAIC and CASC, respectively. The G is about -0.87 and -0.936 eV at 300 K and increases with temperature to obtain -5.47 and

-5.67 eV at 1000 K for CAIC and CASC. Fig. 10b-d illustrates a rapid increase in the specific heat capacity (C_v) from 0 to 147 J mol^{-1} K⁻¹ as the temperature rises from 0 to 500 K. Fig. 10b-d show the relationship between the heat capacity and temperature (0-1000 K). The results show that the heat capacity of the CAIC and CASC has a similar trend; that is, as the temperature increases, the heat capacity C_v increases. In the temperature range of 0 to 396 K, it is observed that the specific heat capacity of CAIC and CASC exhibits an increasing trend with rising temperature. Furthermore, the slope of the curve undergoes a transition from a relatively large to a small value, indicating a gradual approach towards saturation. Eventually, as the temperature approaches approximately 540 K, the specific heat capacity reaches a constant value. When reflecting specifically on the zero-point energies associated with harmonics, the heat capacity at a constant volume of the CAIC and CASC reaches a limiting value of 57.75 and 55.15 J mol⁻¹ K⁻¹ at a temperature of 300 K and 59.43 and 56.2 $I \text{ mol}^{-1} \text{ K}^{-1}$ at a temperature of 1000 K. Furthermore, it is worth noting that the specific heat capacity values pertaining to CAIC is about 249.3 J mol⁻¹ K⁻¹. ¹⁰⁸ For the first time, we report the specific heat capacity of CASC.

Using DFT with the GGA and the PBE functional, the Raman active modes of CAIC and CASC were determined. Based on the theoretical framework of group theory, it is anticipated that the cubic phase, which falls under the $Fm\bar{3}m$ (SG: #225, O_h^5) space group, will exhibit four distinct Raman modes denoted as $\Gamma R = 1A_{1g} + E_g + 2T_{2g}$. The atomic distribution corresponding to this configuration can be found in Fig. 11. The cesium (Cs) and chlorine (Cl) atoms can be found occupying the 8c and 24e

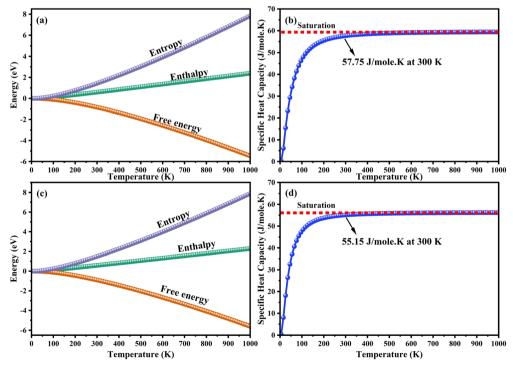


Fig. 10 Temperature dependence of the thermodynamic parameters. (a)-(c) Entropy, enthalpy, free energy and (b)-(d) specific heat capacity at a constant volume of CAIC and CASC compounds.

Wyckoff sites, respectively. These sites are associated with the indication of Raman activity, characterized by the irreducible representations 1A_{1g}, E_g, and 2T_{2g}. The silver (Ag) and indium/ antimony (In/Sb) atoms are positioned at the centers of the octahedral units. The local symmetry of this arrangement, known as O_b symmetry, only affects the infrared modes. In terms of irreducible representation, these modes can be described as T_{1u}. The perovskite structure in challenge exhibits a precisely arranged octahedral network composed of [AgCl₆] and [InCl₆]/[SbCl₆] entities, wherein the translational lattice dynamics arise from the Cs-Cl pair bonding interactions. The observed phenomenon can be attributed to the strong presence of lattice modes (specifically, translation and/or libration) involving Cs interacting with Cl and [BCl₆] entities, resulting in low wavenumber vibrations. In the category of highwavenumber vibrations, the virtual octahedral model emerges as a suitable framework, wherein the internal modes of a single octahedral molecular unit are considered. In this scenario, it is imperative to anticipate the vibrational resonance arising from the molecular ensemble of [InCl₆]/[SbCl₆], as this particular entity exhibits a stronger bonding characteristic in contrast to [AgCl₆]. The presence of silver ions is represented in the vibrational spectrum through the occurrence of rigid displacements of chloride ions.

Yost, Steffens, and Gross have presented the frequencies of the three Raman active modes for a regular octahedral molecule as in the following eqn (9) and (10). 109

$$v_1^2 = (k_{01} + k_{12} + k_{24})/(4\pi^2 m) \tag{9}$$

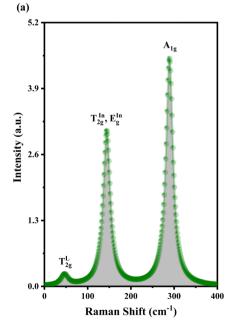
$$v_2^2 = (k_{01} + k_{12} + k_{24} + 3h)/(4\pi^2 m) \tag{10}$$

$$v_3^2 = (2k_{12} - 2h)/(4\pi^2 m) \tag{11}$$

In our investigation, we consider the force constants denoted as k_{01} , k_{12} , and k_{24} . These force constants relate to the interactions occurring between the central atom, which can be Ag, In, or Sb in our specific situation, and a peripheral Cl atom. Also, k_{12} stands for the force constant between two neighboring peripheral Cl atoms, while k_{24} stands for the force constant between two diametrically opposite Cl atoms in an octahedral structure, which is shown by $AgCl_6$, $InCl_6$, and $SbCl_6$. The parameter -h quantifies the relative strength of the repulsive interaction generated by two neighboring Cl atoms, with respect to their equilibrium separation. The variable m represents the mass of the peripheral atom Cl. From the eqn (9) and (10), we can observe the presence of the subsequent interrelation.

$$v_1^2 = v_2^2 + \frac{3}{2}v_3^2 \tag{12}$$

In the context of a regular octahedron, the symbols v_1 , v_2 , and v_3 are representative of the A_{1g} , E_{g} , and T_{2g} modes, respectively. With the help of ab initio calculations, we were able to determine the Raman spectroscopic fingerprint for light with a wavelength of around 520 nm. Through implementing the principles of molecular group theory, we have successfully computed the free vibrations of an isolated octahedral unit composed of [InCl₆]/ [SbCl₆]. The vibrational modes of In/Sb-Cl can be described in terms of their symmetry and corresponding frequencies. The symmetric $A_{1g}(\nu_1)$ mode is observed at 289.49 and 238.98 cm⁻¹. Additionally, the asymmetric $E_g(\nu_2)$ stretchings are found at 144.745 and 170.48 cm⁻¹ for CAIC and CASC, respectively. Furthermore, the symmetric $T_{2g}(\nu_5)$ modes are observed in a regular octahedron, as depicted in Fig. 11. The resultant Raman spectrum includes (i) only one lattice motion in the form of a Cs-Cl translation and (ii) a three-part series of internal octahedral vibrations denoted as ν_1 , ν_2 , and ν_5 . The Raman active modes of



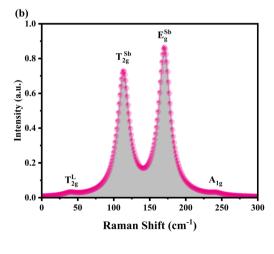


Fig. 11 Calculated Raman active modes at room condition for the ordered cubic (a). CAIC and (b). CASC-compounds.

Table 3 Calculated Raman active modes under room conditions for the ordered cubic CAIC and CASC and their comparison with experimental data

	CAIC		CASC		
Symmetry	$\mathop{\rm Exp.^{110}}_{\left({\rm cm}^{-1}\right)}$	Our study (cm ⁻¹)	$\mathop{\rm Exp.^{111}}_{\left({\rm cm}^{-1}\right)}$	Our study (cm^{-1})	Attribute
T_{2g}^{L}	49	46.36	56	40.37	T
$T_{2g}^{B''}$	142	144.76	118	113.28	\mathbf{v}_5
$T^{L}_{2g} \\ T^{B''}_{2g} \\ E^{B''}_{g}$	166	144.76	217	170.48	\mathbf{v}_2
A_{1g}	300	289.49	288	238.90	$\mathbf{v_1}$

CAIC and CASC, as obtained through experimental measurements and density functional theory (DFT) calculations, are presented in Table 3.

Elastic constants

PCCP

There is a strong relationship between the elastic constants and the basic properties of the material. This is seen in a wide range of process conditions, such as changes in pressure, temperature, agitation, concentration, and heating. The stiffness matrix Cii of cubic crystals refers to the directional mechanical responses of the indicated crystals to various applied forces. Specifically, the coefficients C_{11} , C_{12} , and C_{44} are intimately linked to this matrix, signifying the distinct mechanical behaviors exhibited by the crystals in response to forces generated in different directions. The longitudinal distortion, denoted as C_{11} , has a complex connection to the longitudinal compression and serves as a fundamental description of the associated hardness. The transverse distortion, denoted as C_{12} , is closely related to the transverse expansion, which in turn is deeply connected to the fundamental concept of Poisson's ratio. The shear elastic parameter, denoted as C_{44} , has a complex connection to the shear modulus, which serves as a fundamental measure of the crystal's rigidity. In the framework of this discussion, it is important to note that Table 4 provides a comprehensive overview of elastic constants for HDP. The values of the bulk modulus (B), shear modulus (G), Young's modulus (E), hardness (H), universal anisotropy index (A^{U}) , anisotropy factor in the planes, and Poisson ratio (ν) were obtained via rigorous computational analyses. In cubic crystals, the mechanical strength of the crystals is dependent upon the following conditions:

$$C_{44} > 0$$
, $C_{11} > C_{12}$, $C_{11} + 2C_{12} > 0$ (13)

The values pertaining to the elastic constants for CAIC and CASC are presented in Table 4. The influence of the B"-site cation on these constants appears as an enhancement of C_{11} across the series (Cs₂AgSbCl₆ > Cs₂AgInCl₆), which corresponds with the progressive decrease in the ionic radius of

the B" cation. There was a simultaneous decrease in C-12 along the corresponding trajectory. This observation demonstrates that the B"-site induces an apparent effect on the C_{11} parameter in relation to C_{12} . Consequently, the longitudinal compression exhibits progressively greater significance when contrasted with the transverse and shear distortions. Due to the inequality of C_{11} and $C_{12} + 2C_{44}$, an apparent indication of determined longitudinal distortion, particularly in systems incorporating In and Sb ions, it can be inferred that Cs₂AgB"Cl₆ (where B" represents In or Sb) does not exhibit strict isotropy. In accordance with the Voigt-Reuss Hill (VRH) average scheme, the collective bulk modulus (B), shear modulus (G), and Young's modulus (E) can be obtained by considering the elastic constants. The estimated bulk modulus for the CAIC and CASC systems is 22,959 and 22,623 GPa, respectively. The CAIC exhibits a shear modulus of 11.58 GPa, exceeding that of the CSAC, which measures 7.079 GPa. An increased value of the shear modulus signifies an enhanced extent of interatomic bonding. The Young's modulus, denoted by E, and the Poisson ratio, symbolized by ν , are deeply linked to the shear modulus, represented by G, through the equation E = 9BG/(3B + G). Consequently, it is observed that the Young's modulus exhibits a decreasing impact on physical reliability. In contrast to the other HDPs, the CASC material appears to have an exceptionally elevated Poisson's ratio (ν) of 0.358, owing to the tightly arranged atomic lattice within its structure. Moreover, a decrease in the atomic cross-linking degree is observed together with the enhancement of atomic packing, thereby resulting in an elevation of the Poisson ratio. In relation to the field of particle physics, it is observed that the HDP exhibits a lower dimensionality, suggesting the presence of structures with relatively weaker bonds and a more angular nature of these bonds. This is quantified by a ν value of 0.284 for CAIC. In the study conducted by Pugh et al., 112 it was observed that the brittleness of a material presents itself when the ratio of B to G is less than 1.75. Conversely, a material exhibits ductility when the B/G ratio is significantly large. Our investigation has revealed that the CAIC and CASC materials exhibit ductility, characterized by a higher B/G ratio of 1.98 and 3.19, respectively. The utilization of a universal elastic anisotropy index is employed to examine the evolution of microcracks and the fundamental hardness of materials. The CAIC is characterized by an insignificant value of 0.091, in contrast to the CASC, which possesses a more substantial value of 0.468.

Additionally, using the equation, $H = 2(G^3/B^2)^{0.585} - 3$ it is possible to calculate the hardness (H) of HDP in accordance with Chen's proposed formula. 113 Utilizing the prescribed mathematical expression, the value of H has been determined to be 0.762 and -1.384 GPa for the CAIC and CASC compounds, respectively. The use of the shear anisotropic factor technique

Table 4 Elastic constants (GPa), universal anisotropic index, and Poisson ratio of BN polytypes

Compound	В	G	E	Н	ν	A^{u}	A_1	A_2	A_3
CAIC	22.968	11.58	29.745	$0.762 \\ -1.38$	0.284	0.091	1.8495	1.8495	1.8495
CASC	22.623	7.709	19.23		0.358	0.468	1.3166	1.3166	1.3166

facilitates a greater understanding of the anisotropy associated with the shear modulus across different planes. Based on the discoveries made by Yangthaisong et al., 114 the anisotropic shear factors associated with A_1 , A_2 , and A_3 can be determined by taking into account the orientations of the shear planes, namely 100, 010, and 001, respectively. These quantities can be determined through the utilization of the subsequent mathematical formulations: $A_1 = 4C_{44}/(C_{11} + C_{33} - 2C_{13})$, $A_2 = 4C_{55}/(C_{11} + C_{33})$ $(C_{22} + C_{33} - 2C_{23})$, and $A_3 = 4C_{66}/(C_{11} + C_{22} - 2C_{12})$, correspondingly. A solid material can be considered isotropic when the values of all its properties exhibit a uniform value of 1. The values of A_1 , A_2 , and A_3 for the CAIC and CASC systems exhibit values exceeding unity when subjected to atmospheric pressures of 1.849 and 1.316, respectively. Even though the main conditions are the same, the shear anisotropy factors A_1 , A_2 , and A_3 are not all the same. This is because CAIC and CASC materials are inherently anisotropic. The anisotropic factors exhibit identical characteristics for both the CAIC and CASC compounds.

As part of the Materials Project, 115 the focus is on the 3D analysis and visualization of ELATE, wherein the elastic constants of CAIC and CASC have been employed for the purpose of systematic mechanical characterization. This has been achieved through the utilization of high-throughput calculations pertaining to the elastic constants of inorganic materials, as visually depicted in Fig. 12. The utilization of ELATE (version 2023.01.19, Python 3.10.6), an open-source Python program, is employed for influencing directional elastic characteristics, including the Poisson ratio module, Young's modulus, shear modulus, and spatial dependence on linear compressibility. ELATE provides the second-order elastic constants of C_{ii} s in Voigt notation as a 6×6 systematic matrix for the input stiffness matrix (coefficients in GPa) of CAIC and CASC. The construction of the elastic tensor involves the utilization of six eigenvalues. The material exhibits mechanical stability in the

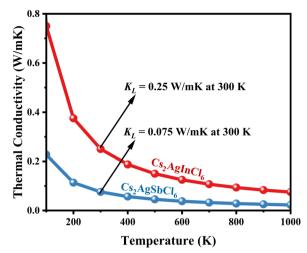


Fig. 13 Calculated ultra-low thermal conductivity of CAIC and CASC compounds via temperature. The thermal conductivity decreases as the temperature increases

presence of positively charged constituents. We observe the physical appearance of Fig. 12(a) and (b), which reveals the complex surface distribution of the elastic modulus of CAIC and CASC, thoroughly portrayed in the three-dimensional (3D) domain. The display of the three-dimensional surface distribution of the blue regions reveals that the anisotropy of the CAIC and CASC increases proportionally with the enhancement of the shear modulus (Fig. 13).

Origin of ultra-low thermal conductivity

In the field of thermoelectric applications, the presence of thermal management materials signifies higher efficiency in thermal conductivity, which signifies the capacity to facilitate heat conduction. Materials with high thermal conductivity are employed to optimize the optoelectronic device's performance.

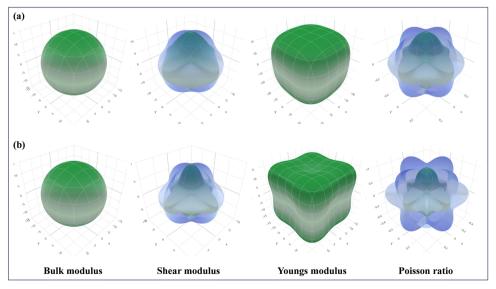


Fig. 12 Spatial dependence of the elastic constants plotted for (a). CAIC and (b). CASC compounds calculated from the online ELATE tool.

The Debye temperature serves as a fundamental measure of the quantum mechanical interactions governing the cohesive forces exhibited by reactive molecular species. 116-118 Through utilization of the Slack model¹¹⁹ and the elastic constants (B and G), we can effectively ascertain the Debye temperature and the Grüneisen parameters associated with the acoustic branches. We estimate the thermal conductivity of CAIC and CASC by using the Slack model to calculate the Debve temperature and the Grüneisen parameters of the acoustic branches, which can be accurately determined by the elastic constants (B and G).

$$K_{\rm L} = A \frac{M_{\rm a} \delta n^{1/3} \Theta^3}{\gamma_{\rm v}^2 T}, \quad A = \frac{2.43 \times 10^{-8}}{1 - \frac{0.514}{\gamma_{\rm v}} + \frac{0.228}{\gamma_{\rm v}^2}}$$
 (14)

Here,
$$A = \frac{2.43 \times 10^{-8}}{1 - \frac{0.514}{\gamma} + \frac{0.228}{\gamma^2}}$$
, $M_{\rm a}$ corresponds to the molar mass,

 δ corresponds to the volume per atom, n corresponds to the number of atoms, Θ corresponds to the Debye acoustic temperature, γ_v corresponds to the acoustic Grüneisen parameter, $k_{\rm B}$ corresponds to the Boltzmann constant, $N_{\rm A}$ corresponds to Avogadro's constant, v_p corresponds to the longitudinal sound velocity, v_s corresponds to the transverse sound velocity, and v_a corresponds to the average sound velocity. To determine Θ , γ_v , v_p , v_s , and v_a the following formulas are used.

$$\Theta = \frac{h}{k_{\rm B}} \left[\frac{3m}{4\pi} \right]^{1/3} v_{\rm a} n^{-1/3}, \quad v_{\rm a} = \left(\frac{1}{3} \left[\frac{1}{v_{\rm t}^3} + \frac{2}{v_{\rm l}^3} \right] \right)^{-1/3} \tag{15}$$

$$v_{\rm p} = \sqrt{G/\rho}, \quad v_{\rm s} = \sqrt{(B + 4G/3)/\rho}$$
 (16)

$$\gamma_{\rm v} = \frac{3}{2} \left(\frac{1+\nu}{2-3\nu} \right), \quad \nu = \frac{1-2(\nu_{\rm t}/\nu_{\rm l})^2}{2-2(\nu_{\rm t}/\nu_{\rm l})^2} \tag{17}$$

Using eqn (15)-(17), we calculate the Θ , $\gamma_{\rm v}$, $\nu_{\rm p}$, $\nu_{\rm s}$, and $\nu_{\rm a}$. The calculated acoustic Debye temperature is about 183 and 145 K for CAIC and CASC compounds, respectively. The longitudinal velocity is about 3086.2 and 2912.7 m s⁻¹, the transverse velocity is about 1694.8 and 1368.7 m s⁻¹, and the average sound velocity is 2841 and 3583 m s⁻¹, respectively. The significance of ultralow thermal conductivity in materials for thermal management cannot be overemphasized, as it exerts a direct influence on the thermoelectric effect. 120-122 Moreover, optoelectronic devices make use of materials possessing elevated thermal conductivity owing to their capacity to reduce the intrinsic noise emerging from the device. 123 The determination of the thermal conductivity of the CAIC and CASC was achieved through the application of the slack model, as elucidated in eqn (15). The thermal conductivities exhibited by CAIC and CASC materials are approximately 0.075 and 0.25 W m⁻¹ K⁻¹, respectively, when subjected to a temperature of 300 K. Moreover, it is important to note that the thermal conductivity values of CAIC and CASC exhibit an enhancement of about 0.41 and 0.5 W m⁻¹ K⁻¹, respectively. 103,124 Our findings indicate a reduction in the specific heat capacity by a factor of five, as well as a reduction in the thermal conductivity by a factor of six for CAIC and a factor of two for CASC. The lattice thermal

conductivity outcomes of CAIC exhibited an apparent resemblance between Cs₂BiAgCl₆ (CABC) and Cs₂BiAgBr₆ (CABB), both of which showed remarkably low values at 0.078 and 0.065 W m^{-1} K⁻¹, respectively. 125 These ultra-low thermal conductivity HDP compounds exhibit important properties such as high electrical conductivity, a positive Seebeck coefficient, and an optimal figure of merit. These attributes render them highly suitable for various thermoelectric applications. 126-128

Conclusions

The analysis of charge transfer in octahedral and intramolecular systems facilitates prediction of the electronic properties, adsorption behavior, and thermodynamic stability of the CAIC and CASC compound and has been been computed by using the density functional theory (DFT) approach. Moreover, the Raman-active modes have been determined using the DFT approach and compared in detail with experimental data. The Raman spectroscopic fingerprint for light with a wavelength of around 520 nm has been obtained via ab initio calculations. The entropy, enthalpy, Helmholtz free energy, and specific heat capacity at a constant volume have been accurately estimated using the quasi-harmonic approximation method to study the thermodynamic properties of materials. The thermal conductivities exhibited using CAIC materials are approximately 0.075 and 0.25 W m⁻¹ K⁻¹, respectively, when subjected to a temperature of 300 K. The findings from our study indicate a remarkably lowered lattice thermal conductivity. This is due to the low phonon group velocity, low Debye temperature, and large phonon scattering within a large-weighted phase space that contribute to this phenomenon.

Conflicts of interest

The authors declare that they have no known competing financial interests or personal relationships that could appear to influence the work reported in this paper.

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